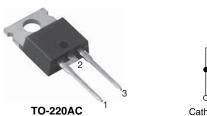


## VS-10ETS...PbF Series, VS-10ETS...M3 Series

Vishay Semiconductors

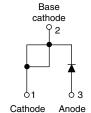
## High Voltage, Input Rectifier Diode, 10 A



 $I_{FSM}$ 

T<sub>J</sub> max.

Diode variation



160 A

150 °C

Single die

PRODUCT SUMMARY					
Package	TO-220AC				
I <sub>F(AV)</sub>	10 A				
V <sub>R</sub>	800 V to 1200 V				
V <sub>F</sub> at I <sub>F</sub>	1.1 V				

#### **FEATURES**

- · Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

#### **DESCRIPTION**

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	12.0	16.0	A		

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	10	Α			
V <sub>RRM</sub>		800/1200	V			
I <sub>FSM</sub>		160	Α			
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.1	V			
T <sub>J</sub>		-40 to +150	°C			

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA			
VS-10ETS08PbF, VS-10ETS08-M3	800	900	0.5			
VS-10ETS12PbF, VS-10ETS12-M3	1200	1300	0.3			



# VS-10ETS...PbF Series, VS-10ETS...M3 Series

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 105 °C, 180° conduction half sine wave	10			
Maximum peak one cycle		10 ms sine pulse, rated V <sub>RRM</sub> applied	135	Α		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	160			
Marries un 12t fau frain a	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	91	A <sup>2</sup> s		
Maximum I <sup>2</sup> t for fusing		10 ms sine pulse, no voltage reapplied	130	A <sup>z</sup> S		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	1300	A <sup>2</sup> √s		

ELECTRICAL SPECIFICATIONS						
PARAMETER SYMBOL TEST CONDITIONS					UNITS	
Maximum forward voltage drop	$V_{FM}$	10 A, T <sub>J</sub> = 25 °C	1.1	V		
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C	20	mΩ		
Threshold voltage	V <sub>F(TO)</sub>	1 IJ = 150 C	0.82	V		
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	V - Poted V	0.05	mΛ	
Maximum reverse leakage current		T <sub>J</sub> = 150 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	0.50	mA	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5			
Maximum thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub>		62	°C/W		
Soldering temperature	Ts		240	°C		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Marking device		One of the TO 0004 O	10ETS08			
ivial killig device		Case style TO-220AC	10ET	TS12		





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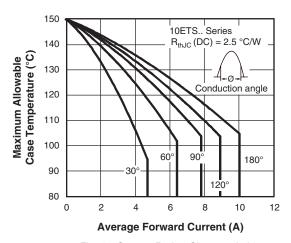


Fig. 1 - Current Rating Characteristics

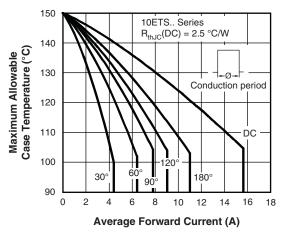


Fig. 2 - Current Rating Characteristics

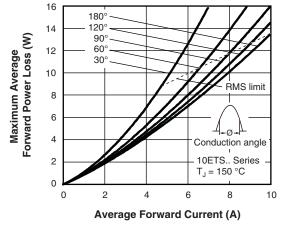


Fig. 3 - Forward Power Loss Characteristics

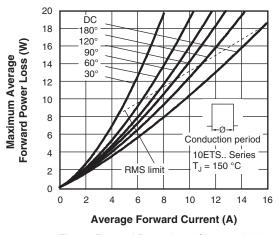


Fig. 4 - Forward Power Loss Characteristics

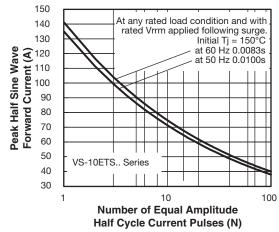


Fig. 5 - Maximum Non-Repetitive Surge Current

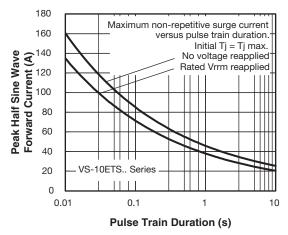


Fig. 6 - Maximum Non-Repetitve Surge Current

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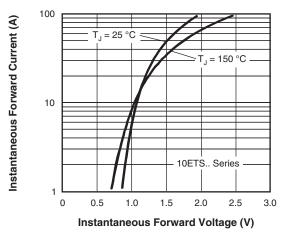


Fig. 7 - Forward Voltage Drop Characteristics

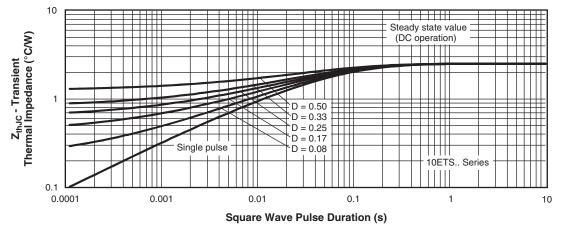


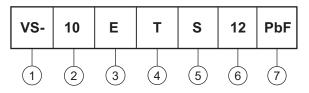
Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

## VS-10ETS...PbF Series, VS-10ETS...M3 Series

Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

3 - Circuit configuration:

E = single diode

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage code x 100 = V<sub>RRM</sub> - 08 = 800 V 12 = 1200 V

7 - Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETS08PbF	50	1000	Antistatic plastic tubes			
VS-10ETS08-M3	50	1000	Antistatic plastic tubes			
VS-10ETS12PbF	50	1000	Antistatic plastic tubes			
VS-10ETS12-M3	50	1000	Antistatic plastic tubes			

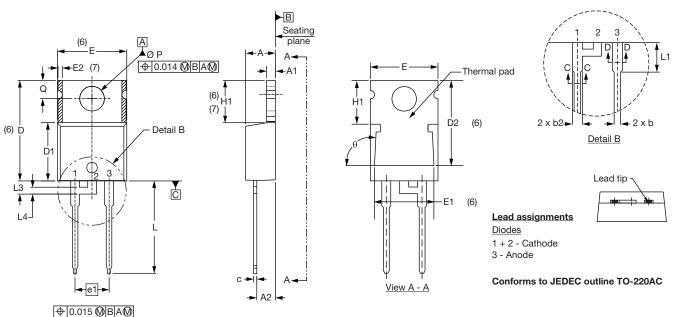
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95221			
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224			
Part marking information	TO-220AC -M3	www.vishay.com/doc?95068			



### Vishay Semiconductors

### **TO-220AC**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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